

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP290

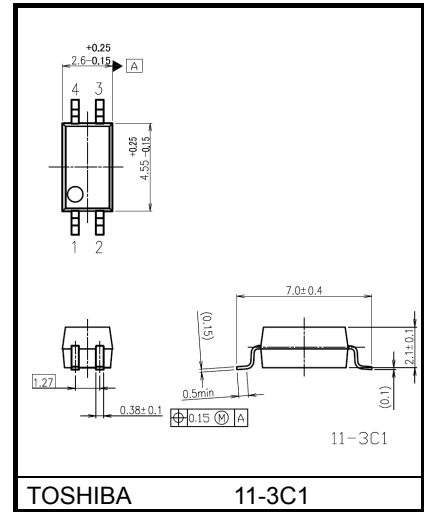
Programmable Controllers  
 AC/DC-Input Module  
 Hybrid ICs

TLP290 consist of photo transistor, optically coupled to two gallium arsenide infrared emitting diode connected inverse parallel, and can operate directly by AC input current

Since TLP290 are guaranteed wide operating temperature (Ta=-55 to 110 °C) and high isolation voltage (3750Vrms), it's suitable for high-density surface mounting applications such as programmable controllers and hybrid ICs.

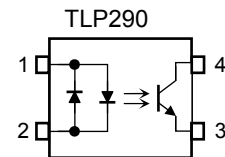
- Collector-Emitter voltage : 80 V (min)
- Current transfer ratio : 50% (min)  
     Rank GB : 100% (min)
- Isolation voltage : 3750 Vrms (min)
- Guaranteed performance over -55 to 110 °C
  
- UL(Under application): UL1577
- cUL(Under application): CSA Component Acceptance Service No.5A
- SEMKO(Under application):EN 60065: 2002,  
     EN 60950-1: 2001, EN 60335-1: 2002
- BSI (Under application): BS EN 60065: 2002,  
     BS EN 60950-1: 2006
  
- Option (V4)  
     VDE (Under application): EN60747-5-2

Unit: mm



Weight: 0.05 g (typ.)

## Pin Configuration



- 1: Anode  
     Cathode
- 2: Cathode  
     Anode
- 3: Emitter
- 4: Collector

## Current Transfer Ratio (Unless otherwise specified, Ta = 25°C)

TYPE	Classification (Note1)	Current Transfer Ratio (%) (I <sub>C</sub> / I <sub>F</sub> )		Marking of Classification
		I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V, Ta = 25°C		
		Min	Max	
TLP290	Blank	50	400	Blank, YE, GR, B, GB
	Rank Y	50	150	YE
	Rank GR	100	300	GR
	Rank BLL	200	400	B
	Rank GB	100	400	GB

Note1: Ex. rank GB: TLP290(GB,E)

Note Application type name for certification test, please use standard product type name, i.e.

TLP290(GB,E): TLP290

## Absolute Maximum Ratings (Note) (Unless otherwise specified, Ta = 25°C)

Characteristic		Symbol	Note	Rating	Unit
LED	R.M.S. forward current	I <sub>F(RMS)</sub>		±50	mA
	Input forward current derating (Ta ≥ 90°C)	ΔI <sub>F</sub> / ΔTa		-1.5	mA / °C
	Input forward current (pulsed)	I <sub>FP</sub>	(Note 2)	±1	A
	Input power dissipation	P <sub>D</sub>		100	mW
	Input power dissipation derating (Ta ≥ 90°C)	ΔP <sub>D</sub> / ΔTa		-3.0	mW / °C
	Junction temperature	T <sub>j</sub>		125	°C
Detector	Collector-emitter voltage	V <sub>CEO</sub>		80	V
	Emitter-collector voltage	V <sub>ECO</sub>		7	V
	Collector current	I <sub>C</sub>		50	mA
	Collector power dissipation	P <sub>C</sub>		150	mW
	Collector power dissipation derating (Ta ≥ 25°C)	ΔP <sub>C</sub> / ΔTa		-1.5	mW / °C
	Junction temperature	T <sub>j</sub>		125	°C
Operating temperature range		T <sub>opr</sub>		-55 to 110	°C
Storage temperature range		T <sub>stg</sub>		-55 to 125	°C
Lead soldering temperature		T <sub>sol</sub>		260 (10s)	°C
Total package power dissipation		P <sub>T</sub>		200	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP <sub>T</sub> / ΔTa		-2.0	mW / °C
Isolation voltage		BV <sub>S</sub>	(Note3)	3750	V <sub>rms</sub>

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note2: Pulse width ≤ 100μs, frequency 100Hz

Note3: AC, 1min., R.H. ≤ 60%, Device considered a two terminal device: LED side pins shorted together and detector side pins shorted together.

**Electrical Characteristics (Unless otherwise specified, Ta = 25°C)**

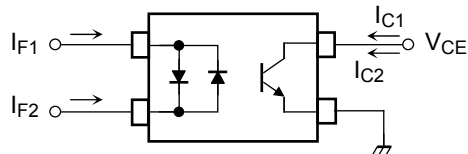
Characteristic		Symbol	Test Condition	Min	Typ	Max	Unit
LED	Input forward voltage	$V_F$	$I_F = \pm 10 \text{ mA}$	1.1	1.25	1.4	V
	Input capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	60	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	80	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Dark current	$I_{CEO}$	$V_{CE} = 48 \text{ V},$	—	0.01	0.08	$\mu\text{A}$
			$V_{CE} = 48 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	$\mu\text{A}$
Collector-emitter capacitance	$C_{CE}$	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	

**Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	$I_C / I_F$	$I_F = \pm 5 \text{ mA}, V_{CE} = 5 \text{ V}$ Rank GB	50	—	400	%
			100	—	400	
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = \pm 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$ Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	$V_{CE} (\text{sat})$	$I_C = 2.4 \text{ mA}, I_F = \pm 8 \text{ mA}$ $I_C = 0.2 \text{ mA}, I_F = \pm 1 \text{ mA}$ Rank GB	—	—	0.3	V
			—	0.2	—	
			—	—	0.3	
Off-state collector current	$I_{C(\text{off})}$	$V_F = \pm 0.7 \text{ V}, V_{CE} = 48 \text{ V}$	—	—	10	$\mu\text{A}$
Collector current ratio	$I_C (\text{ratio})$	$I_C (I_F = -5 \text{ mA}) / I_C (I_F = 5 \text{ mA})$ (Fig.1)	0.33	—	3	—

Fig. 1: Collector current ratio test circuit

$$I_C(\text{ratio}) = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$$



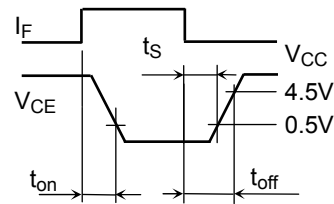
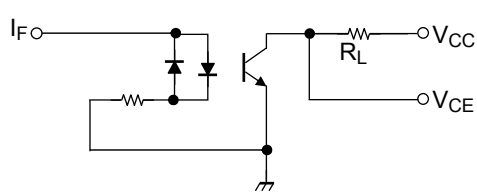
## Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Total capacitance (input to output)	C <sub>S</sub>	V <sub>S</sub> = 0V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> = 500 V, R.H. ≤ 60%	1×10 <sup>12</sup>	10 <sup>14</sup>	—	Ω
Isolation voltage	BV <sub>S</sub>	AC, 1 minute	3750	—	—	V <sub>rms</sub>
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	V <sub>dc</sub>

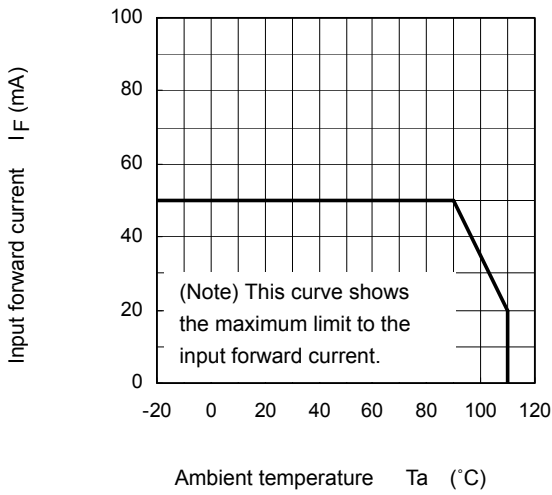
## Switching Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t <sub>r</sub>	V <sub>CC</sub> = 10 V, I <sub>C</sub> = 2 mA R <sub>L</sub> = 100 Ω	—	4	—	μs
Fall time	t <sub>f</sub>		—	7	—	
Turn-on time	t <sub>on</sub>		—	7	—	
Turn-off time	t <sub>off</sub>		—	7	—	
Turn-on time	t <sub>on</sub>	R <sub>L</sub> = 1.9 kΩ V <sub>CC</sub> = 5 V, I <sub>F</sub> = ±16 mA (Fig.2)	—	2	—	μs
Storage time	t <sub>s</sub>		—	30	—	
Turn-off time	t <sub>off</sub>		—	60	—	

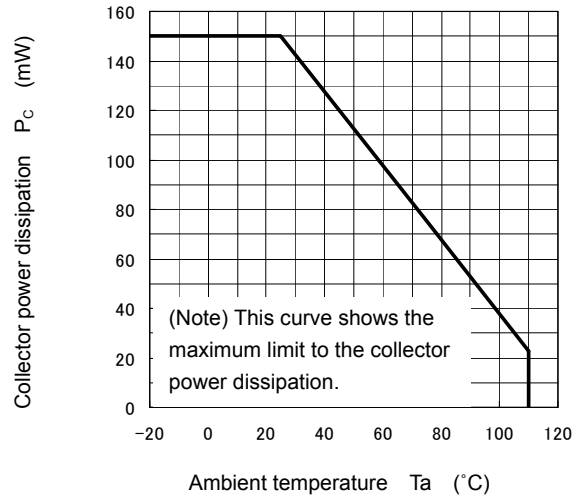
(Fig. 2): Switching time test circuit



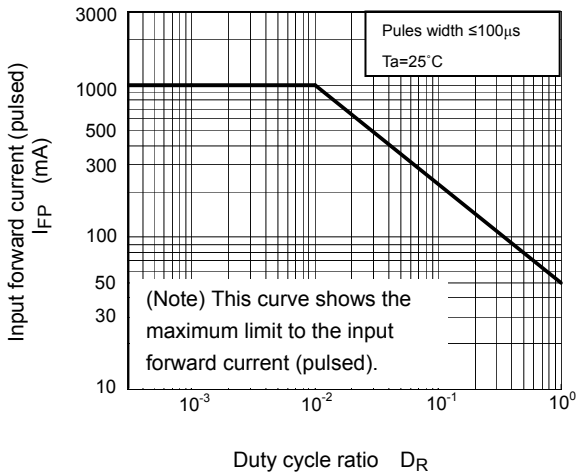
$I_F - T_a$



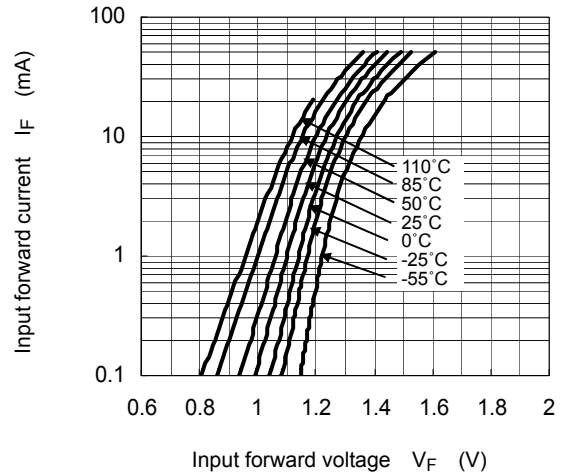
$P_C - T_a$



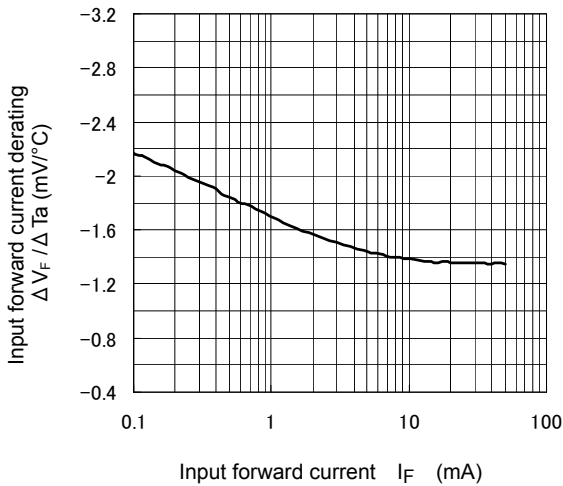
$I_{FP} - D_R$



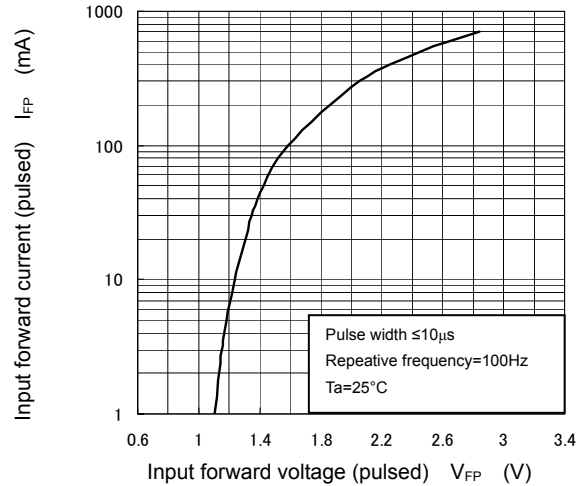
$I_F - V_F$



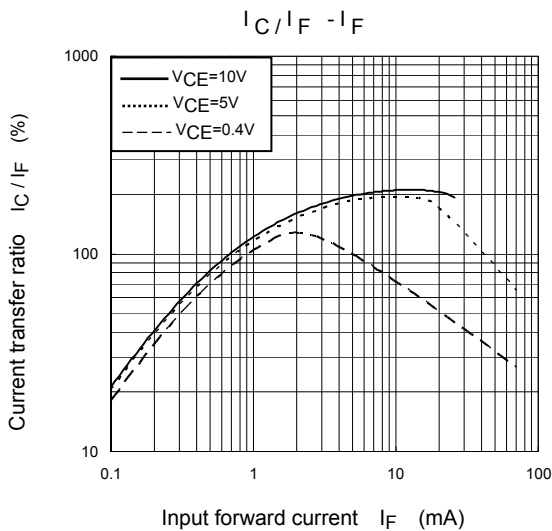
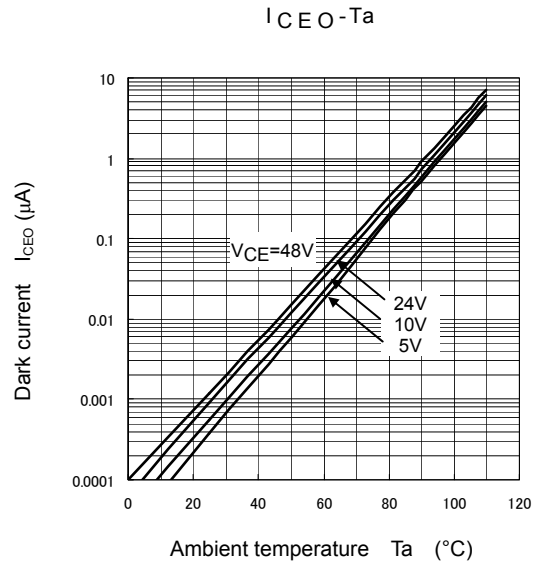
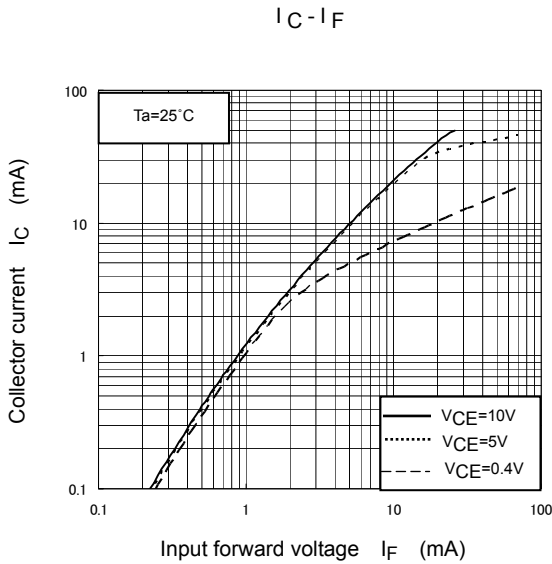
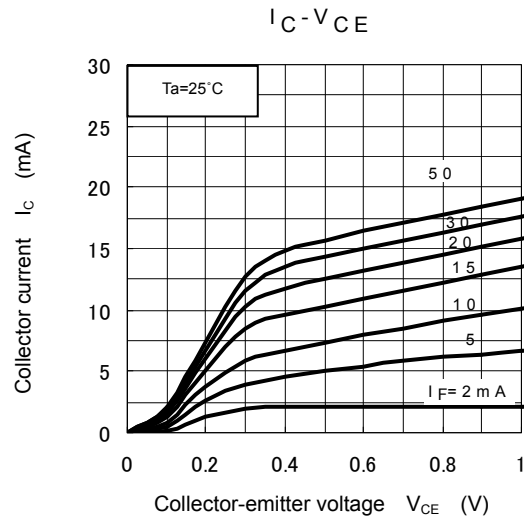
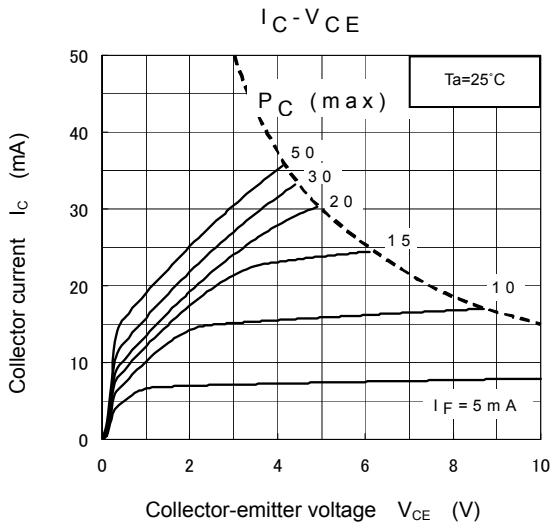
$\Delta V_F / \Delta T_a - I_F$



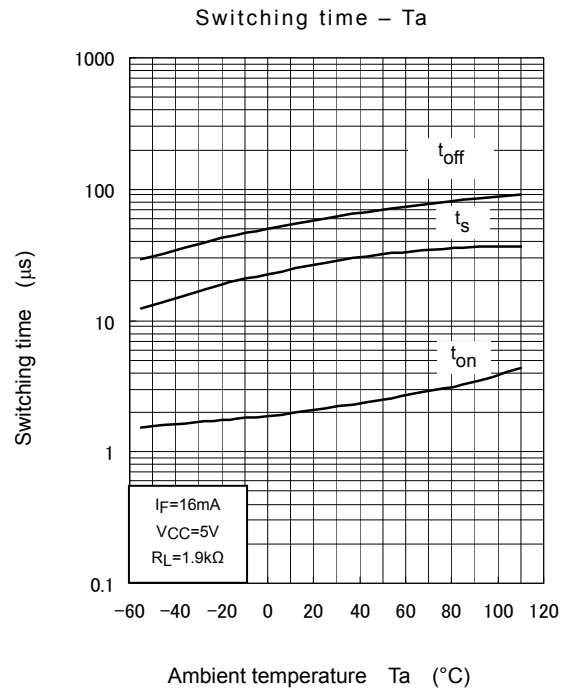
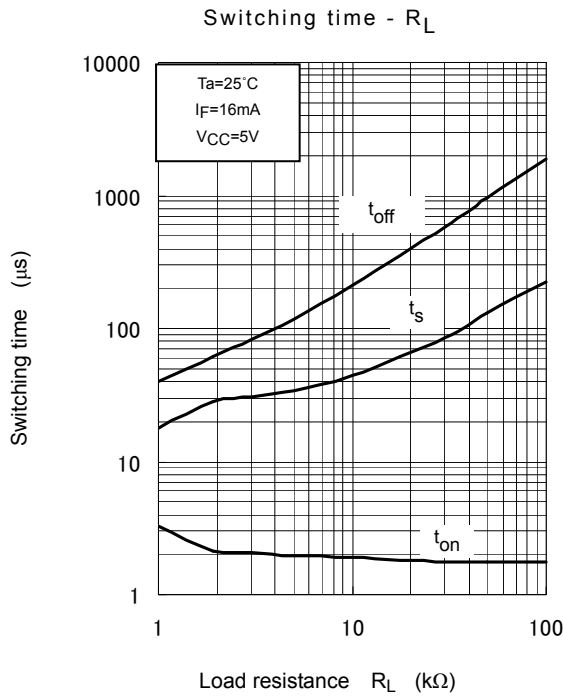
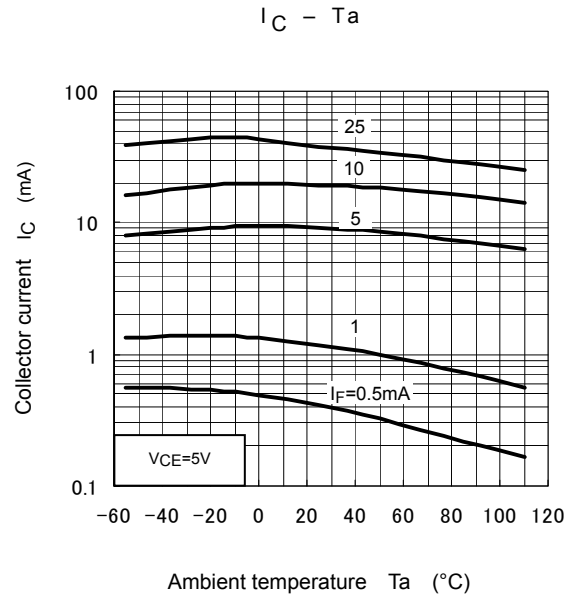
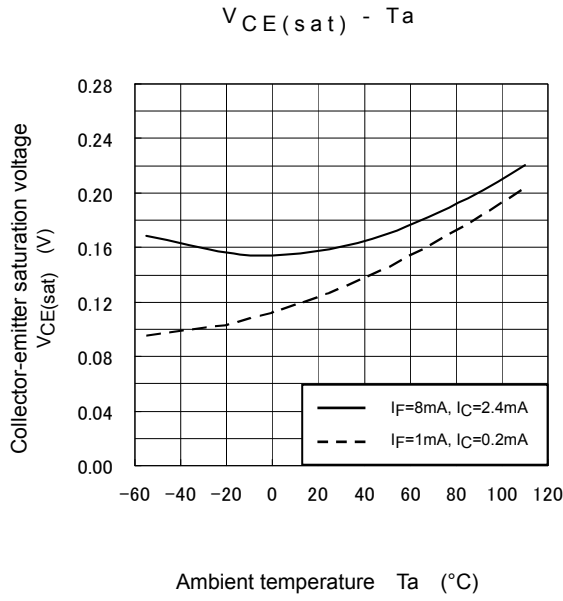
$I_{FP} - V_{FP}$



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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## Soldering and Storage

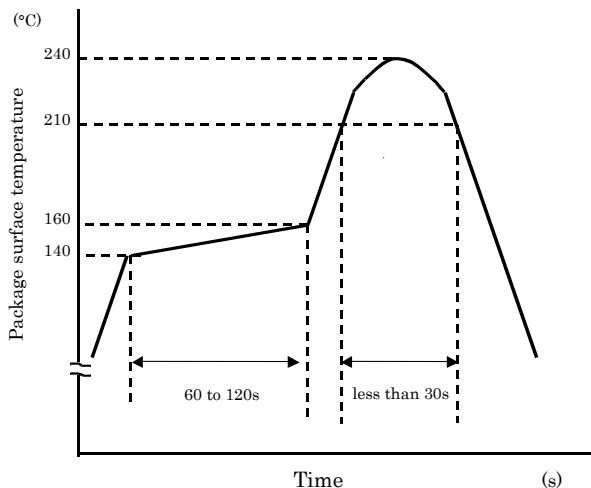
### 1. Soldering

#### 1.1 Soldering

When using a soldering iron or medium infrared ray/hot air reflow, avoid a rise in device temperature as much as possible by observing the following conditions.

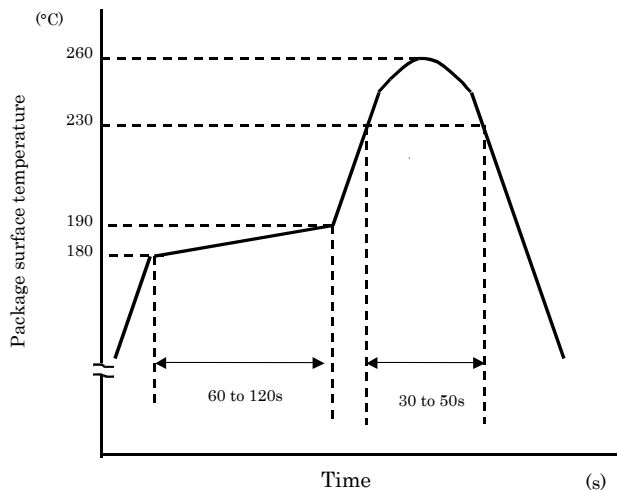
#### 1) Using solder reflow

·Temperature profile example of lead (Pb) solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

·Temperature profile example of using lead (Pb)-free solder



This profile is based on the device's maximum heat resistance guaranteed value. Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

#### 2) Using solder flow (for lead (Pb) solder, or lead (Pb)-free solder)

- Please preheat it at 150°C between 60 and 120 seconds.
- Complete soldering within 10 seconds below 260°C. Each pin may be heated at most once.

#### 3) Using a soldering iron

Complete soldering within 10 seconds below 260°C, or within 3 seconds at 350°C. Each pin may be heated at most once.



**2. Storage**

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

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